

U74LVC1G86

CMOS IC

SINGLE 2-INPUT EXCLUSIVE-OR GATE

■ DESCRIPTION

The **U74LVC1G86** is a single 2-input EXCLUSIVE-OR gate which provides the Function $Y = A \oplus B$ or $Y = \overline{AB} + \overline{A}\overline{B}$ in positive logic. Inputs can be driven from either 3.3V or 5V devices. These features allow the use of these devices in a mixed 3.3V and 5V environment.

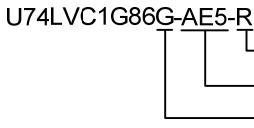
This device is fully specified for partial Power-down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

■ FEATURES

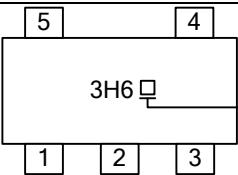
- * Operate from 1.65V to 5.5V
- * Inputs accept voltages to 5.5V
- * I_{OFF} supports partial-power-down mode
- * Low power dissipation
- * Max t_{PD} of 4 ns at 3.3V

■ ORDERING INFORMATION

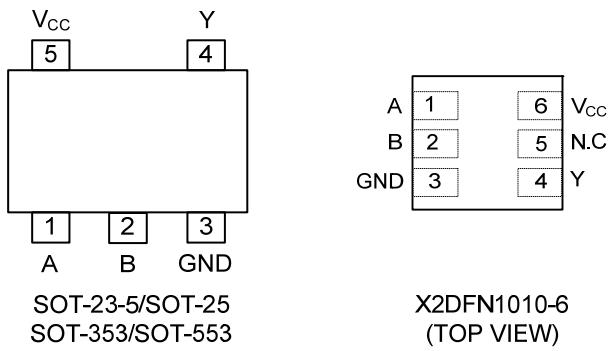
Ordering Number		Package	Packing
Lead Free	Halogen Free		
U74LVC1G86L-AE5-R	U74LVC1G86G-AE5-R	SOT-23-5	Tape Reel
U74LVC1G86L-AF5-R	U74LVC1G86G-AF5-R	SOT-25	Tape Reel
U74LVC1G86L-AL5-R	U74LVC1G86G-AL5-R	SOT-353	Tape Reel
U74LVC1G86L-AN5-R	U74LVC1G86G-AN5-R	SOT-553	Tape Reel
U74LVC1G86L-K06-1010X2-R	U74LVC1G86G-K06-1010X2-R	X2DFN1010-6	Tape Reel

 (1)Packing Type (2)Package Type (3)Green Package	(1) R: Tape Reel (2) AE5: SOT-23-5, AF5: SOT-25, AL5: SOT-353 AN5: SOT-553, K06-1010X2: X2DFN1010-6 (3) G: Halogen Free and Lead Free, L: Lead Free
-----------------------------------------------------------------------------------------------------------------------------------------------	--------------------------------------------------------------------------------------------------------------------------------------------------------------

■ MARKING

SOT-23-5 / SOT-25 / SOT-353 / SOT-553  3H6 □ L: Lead Free G: Halogen Free	X2DFN1010-6  H6 •
--------------------------------------------------------------------------------------------------------------------------------------------------------------------------	-----------------------------------------------------------------------------------------------------------------

■ PIN CONFIGURATION



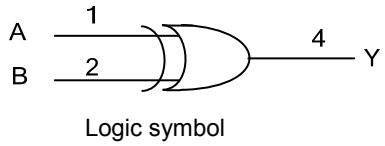
■ FUNCTION TABLE

INPUT(A)	INPUT(B)	OUTPUT(Y)
L	L	L
H	L	H
L	H	H
H	H	L

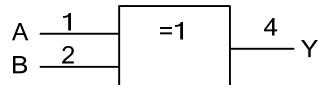
Note: H: HIGH voltage level; L: LOW voltage level

■ LOGIC DIAGRAM (positive logic)

For SOT-23-5/SOT-25/SOT-353/SOT-553

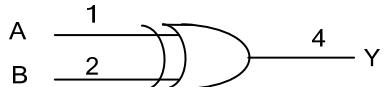


Logic symbol

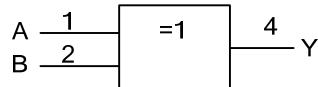


IEC logic symbol

For X2DFN1010-6



Logic symbol



IEC logic symbol

■ ABSOLUTE MAXIMUM RATING

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage	V _{CC}	-0.5 ~ +6.5	V
Input Voltage	V _{IN}	-0.5 ~ +6.5	V
Output Voltage	V _{OUT}	-0.5 ~ V _{CC} +0.5	V
		-0.5 ~ +6.5	V
Continuous V _{CC} or GND Current	I _{CC}	±100	mA
Continuous Output Current (V _{OUT} =0 to V _{CC})	I _{OUT}	±50	mA
Input Clamp Current (V _{IN} <0)	I _{IK}	-50	mA
Output Clamp Current (V _{OUT} <0)	I _{OK}	-50	mA
Storage Temperature Range	T _{STG}	-65 ~ +150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Supply Voltage	V _{CC}	Operating	1.65		5.5	V
		Data retention only	1.5			V
Input Voltage	V _{IN}		0		5.5	V
Output Voltage	V _{OUT}	High or low state	0		V _{CC}	V
High-level Output Current	I _{OH}	V _{CC} =1.65V			-4	mA
		V _{CC} =2.3V			-8	mA
		V _{CC} =3V			-16	mA
		V _{CC} =3V			-24	mA
		V _{CC} =4.5V			-32	mA
Low-level Output Current	I _{OL}	V _{CC} =1.65V			4	mA
		V _{CC} =2.3V			8	mA
		V _{CC} =3V			16	mA
		V _{CC} =3V			24	mA
		V _{CC} =4.5V			32	mA
Input Transition Rise or Fall Rate	Δt/Δv	V _{CC} =1.8V±0.15V, 2.5V±0.2V			20	ns/V
		V _{CC} =3.3V±0.3V			10	ns/V
		V _{CC} =5V±0.5V			5	ns/V
Operating Temperature	T _A		-40		+125	°C

■ ELECTRICAL CHARACTERISTICS ($T_A=25^\circ C$, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
High-level Input Voltage	V_{IH}	$V_{CC}=1.65V \text{ to } 1.95V$	$0.65 \times V_{CC}$			V
		$V_{CC}=2.3V \text{ to } 2.7V$	1.7			V
		$V_{CC}=3V \text{ to } 3.6V$	2			V
		$V_{CC}=4.5V \text{ to } 5.5V$	$0.7 \times V_{CC}$			V
Low-level Input Voltage	V_{IL}	$V_{CC}=1.65V \text{ to } 1.95V$		$0.35 \times V_{CC}$		V
		$V_{CC}=2.3V \text{ to } 2.7V$		0.7		V
		$V_{CC}=3V \text{ to } 3.6V$		0.8		V
		$V_{CC}=4.5V \text{ to } 5.5V$		$0.3 \times V_{CC}$		V
High-Level Output Voltage	V_{OH}	$V_{CC}=1.65 \sim 5.5V, I_{OH}=-100\mu A$	$V_{CC}-0.1$			V
		$V_{CC}=1.65V, I_{OH}=-4mA$	1.2			V
		$V_{CC}=2.3V, I_{OH}=-8mA$	1.9			V
		$V_{CC}=3.0V$	$I_{OH}=-16mA$	2.4		V
			$I_{OH}=-24mA$	2.3		V
Low-Level Output Voltage	V_{OL}	$V_{CC}=4.5V, I_{OH}=-32mA$	3.8			V
		$V_{CC}=1.65 \sim 5.5V, I_{OL}=100\mu A$		0.1		V
		$V_{CC}=1.65V, I_{OL}=4mA$		0.45		V
		$V_{CC}=2.3V, I_{OL}=8mA$		0.3		V
		$V_{CC}=3.0V$	$I_{OL}=16mA$	0.4		V
			$I_{OL}=24mA$	0.55		V
Input Leakage Current	$I_{I(LEAK)}$	$V_{CC}=4.5V, I_{OL}=32mA$		0.55		V
		$V_{CC}=0 \sim 5.5V, V_{IN}=5.5V \text{ or GND}$		± 5	μA	
		$V_{CC}=0V, V_{IN} \text{ or } V_{OUT}=5.5V$		± 10	μA	
		$V_{CC}=1.65 \sim 5.5V, V_{IN}=V_{CC} \text{ or GND}, I_{OUT}=0$		10	μA	
		$V_{CC}=3 \sim 5.5V, \text{One input at } V_{CC}-0.6V, \text{Other inputs at } V_{CC} \text{ or GND}$		500	μA	
		$V_{CC}=3.3V, V_{IN}=V_{CC} \text{ or GND}$		6		pF

■ SWITCHING CHARACTERISTICS ($T_A=25^\circ C$, unless otherwise specified)

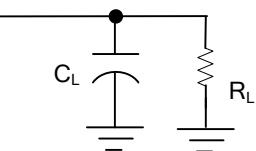
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Propagation delay from input to output	t_{PLH}	$V_{CC}=1.8 \pm 0.15V, C_L=15pF, R_L=1M\Omega$	2.1		9.1	ns
		$V_{CC}=2.5 \pm 0.2V, C_L=15pF, R_L=1M\Omega$	1		4.5	ns
		$V_{CC}=3.3 \pm 0.3V, C_L=15pF, R_L=1M\Omega$	0.6		4	ns
		$V_{CC}=5 \pm 0.5V, C_L=15pF, R_L=1M\Omega$	0.8		3.3	ns
Propagation delay from input to output	t_{PHL}	$V_{CC}=1.8 \pm 0.15V, C_L=30pF, R_L=1K\Omega$	3.5		9.9	ns
		$V_{CC}=2.5 \pm 0.2V, C_L=30pF, R_L=500\Omega$	1.8		5.5	ns
		$V_{CC}=3.3 \pm 0.3V, C_L=50pF, R_L=500\Omega$	1.3		5	ns
		$V_{CC}=5 \pm 0.5V, C_L=50pF, R_L=500\Omega$	1		4	ns

■ OPERATING CHARACTERISTICS ($f=10MHz, T_A=25^\circ C$, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Power Dissipation Capacitance	C_{PD}	$V_{CC}=1.8V$		22		pF
		$V_{CC}=2.5V$		22		pF
		$V_{CC}=3.3V$		22		pF
		$V_{CC}=5V$		24		pF

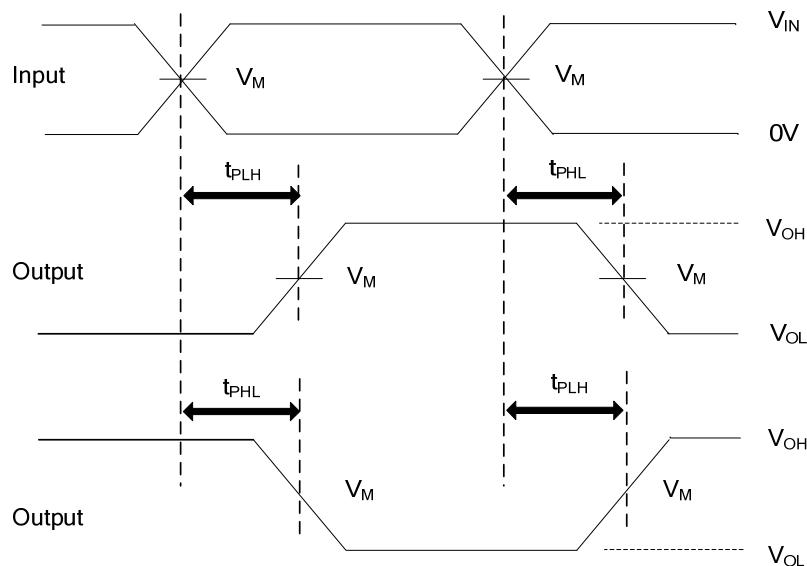
■ TEST CIRCUIT AND WAVEFORMS

From Output



TEST CIRCUIT

V_{CC}	Inputs		V_M	C_L	R_L
	V_{IN}	t_R, t_F			
$1.8V \pm 0.15V$	V_{CC}	$\leq 2ns$	$V_{CC}/2$	15pF	1MΩ
				30pF	1KΩ
$2.5V \pm 0.2V$	V_{CC}	$\leq 2ns$	$V_{CC}/2$	15pF	1MΩ
				30pF	500Ω
$3.3V \pm 0.3V$	$3V$	$\leq 2.5ns$	$1.5V$	15pF	1MΩ
				50pF	500Ω
$5V \pm 0.5V$	V_{CC}	$\leq 2.5ns$	$V_{CC}/2$	15pF	1MΩ
				50pF	500Ω



PROPAGATION DELAY TIMES

Notes: 1. C_L includes probe and jig capacitance.

2. All input pulses are supplied by generators having the following characteristics: PRR $\leq 10MHz$, $Z_0 = 50\Omega$.

UTC assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all UTC products described or contained herein. UTC products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. UTC reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.